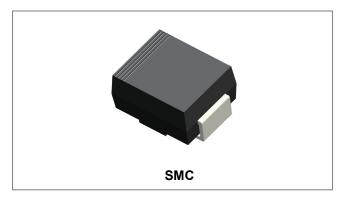






## 30BQ040 SCHOTTKY RECTIFIER



#### **Features**

- Small foot print, surface moutable
- Low forward voltage drop
- · High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Circuit Diagram**



#### **Applications**

- Disk Drives
- Switching power supply
- Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery Charging

#### Maximum Ratings@T<sub>A</sub>=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$	-	40	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>C</sub> =118°C, rectangular wave form	3.0	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	80	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 3 A, Pulse, T <sub>J</sub> = 25 °C	0.47	0.53	V
		@ 6 A, Pulse, T <sub>J</sub> = 25 °C	0.58	0.68	V
	$V_{F2}$	@ 3 A, Pulse, T <sub>J</sub> = 125 °C	0.42	0.43	V
		@ 6 A, Pulse, T <sub>J</sub> = 125°C	0.56	0.57	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = Rated V <sub>R</sub> , Pulse, T <sub>J</sub> = 25 °C	0.04	0.5	mA
	$I_{R2}$	@V <sub>R</sub> = Rated V <sub>R</sub> , Pulse, T <sub>J</sub> = 100 °C	-	30	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	167	230	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	3.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +125	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Lead	R <sub>θJL</sub>	-	12	°C/W
Typical Thermal Resistance Junction to Case	R <sub>θJA</sub>	DC operation	46	°C/W
Approximate Weight	wt	-	0.21	g
Case Style	SMC			

# **Ratings and Characteristics Curves**

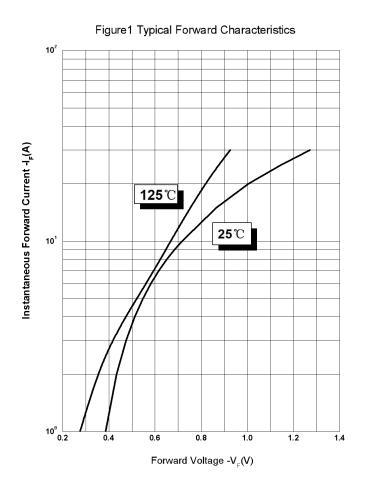


Figure 2 Typical Reverse Characteristics

Parameter 10<sup>2</sup>

10<sup>1</sup>

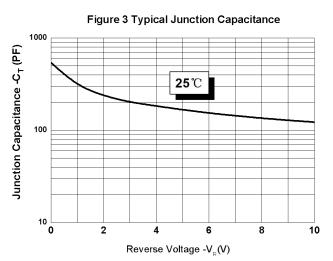
10<sup>1</sup>

10<sup>2</sup>

10<sup>3</sup>

10<sup>3</sup>

Reverse Voltage -V<sub>p</sub>(V)



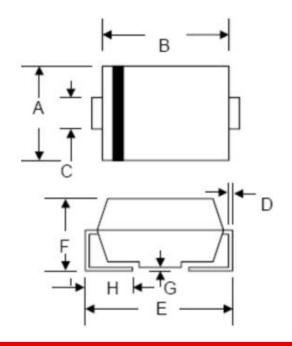
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### **Mechanical Dimensions SMC**



CVMDOL	Millin	neters	Inches		
SYMBOL	Min.	Max.	Min.	Max.	
А	5.59	6.22	0.220	0.245	
В	6.60	7.11	0.260	0.280	
С	2.75	3.25	0.108	0.128	
D	0.152	0.305	0.006	0.012	
E	7.75	8.25	0.305	0.325	
F	2.00	2.95	0.079	0.116	
G	0.051	0.203	0.002	0.008	
Н	0.76	1.60	0.030	0.063	

### **Ordering Information**

Device	Package	Shipping
30BQ040	SMC (Pb-Free)	3000pcs / reel
30BQ040TR	SMC (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**

SC3F XXXXX Where XXXXX is YYWWL

 SC3F
 = Part Name

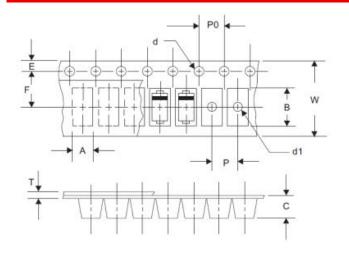
 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

## **Carrier Tape Specification SMC**



SYMBOL	Millimeters		
	Min.	Max.	
Α	5.95	6.15	
В	8.10	8.30	
С	2.60	2.80	
d	1.40	1.60	
E	1.65	1.85	
F	7.40	7.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.20	0.40	
W	15.70	16.30	

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